



### **600V N-Channel MOSFET**

Voltage

600 V

**Current** 

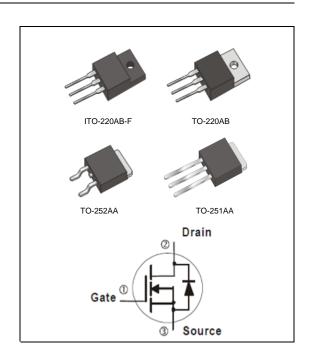
4 A

#### **Features**

- R<sub>DS(ON)</sub>, V<sub>GS</sub>@10V,I<sub>D</sub>@2A<2.4Ω
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

### **Mechanical Data**

- Case: TO-251AA,TO-252AA,TO-220AB, ITO-220AB-F Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- TO-251AA Approx. Weight: 0.0104 ounces, 0.297grams
- TO-252AA Approx. Weight: 0.0104 ounces, 0.297grams
- TO-220AB Approx. Weight: 0.067 ounces, 1.9 grams
- ITO-220AB-F Approx. Weight: 0.068 ounces, 2 grams



# **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER		SYMBOL	TO-251AA	TO-220AB	ITO-220AB-F	TO-252AA	UNITS
Drain-Source Voltage		$V_{DS}$	600				V
Gate-Source Voltage		$V_{GS}$	<u>+</u> 30				V
Continuous Drain Current		$I_{D}$	4				Α
Pulsed Drain Current		I <sub>DM</sub>	16				Α
Single Pulse Avalanche Energy (Note 1)		E <sub>AS</sub>	217				mJ
Power Dissipation	T <sub>C</sub> =25°C	P <sub>D</sub>	77	100	33	77	W
	Derate above 25°C		0.62	0.8	0.26	0.62	W/°C
Operating Junction and		$T_J$ , $T_{STG}$	55, 450				
Storage Temperature Range			-55~150				°C
Typical Thermal resistance							
- Junction to Case		$R_{ heta JC}$	1.62	1.25	3.79	1.62	°C/W
- Junction to Ambient		$R_{ heta JA}$	110	62.5	120	110	

• Limited only By Maximum Junction Temperature





# PJU4NA60 / PJD4NA60 / PJF4NA60

# Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V,I <sub>D</sub> =250uA	600	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250uA$	2	3.2	4	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	$V_{GS}$ =10V, $I_D$ =2A	-	1.92	2.4	Ω
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =600V,V <sub>GS</sub> =0V	-	0.03	1.0	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 30V,V <sub>DS</sub> =0V	-	<u>+</u> 10	<u>+</u> 100	nA
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =4A,V <sub>GS</sub> =0V	-	0.86	1.4	V
Dynamic (Note 4)						
Total Gate Charge	$Q_g$	\/ 400\/ L 4A	-	11.1	-	nC
Gate-Source Charge	$Q_{gs}$	$V_{DS}$ =480V, $I_{D}$ =4A, $V_{GS}$ =10V (Note 2,3)	-	3.3	-	
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =10V	-	4.2	-	
Input Capacitance	Ciss	\\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	-	450	-	pF
Output Capacitance	Coss	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V,	-	67	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	0.7	-	
Turn-On Delay Time	td <sub>(on)</sub>		-	10	-	ns
Turn-On Rise Time	t <sub>r</sub>	$V_{DD}$ =300V, $I_{D}$ =4A,	-	23	-	
Turn-Off Delay Time	td <sub>(off)</sub>	$R_G=25\Omega$ (Note 2,3)	-	24	-	
Turn-Off Fall Time	t <sub>f</sub>		-	24	-	
Drain-Source Diode						
Maximum Continuous Drain-Source			-	-	4	А
Diode Forward Current	l <sub>S</sub>					
Maximum Pulsed Drain-Source					16	^
Diode Forward Current	e Forward Current		_	- 10	16	A
Reverse Recovery Time	trr	V <sub>GS</sub> =0V, I <sub>S</sub> =4A	-	400	-	ns
Reverse Recovery Charge	Qrr	dI <sub>F</sub> / dt=100A/us (Note 2)	-	1.7	-	uC

#### NOTES:

- 1. L=30mH,  $I_{AS}$ =3.7A,  $V_{DD}$ =50V,  $R_{G}$ =25ohm, Starting  $T_{J}$ =25 $^{\circ}$ C
- 2. Pulse width<a></a>300us, Duty cycle<a></a>2%
- 3. Essentially independent of operating temperature typical characteristics.
- 4. Guaranteed by design, not subject to production testing





#### **TYPICAL CHARACTERISTIC CURVES**

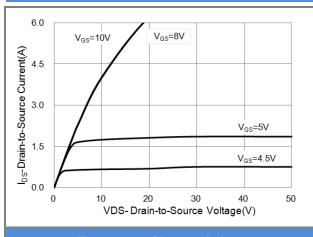
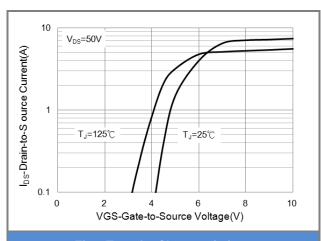


Fig.1 Output Characteristics



**Fig.2 Transfer Characteristics** 

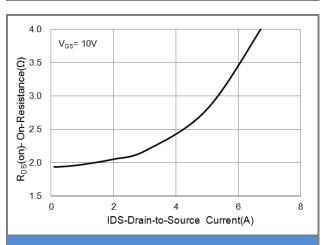


Fig.3 On-Resistance vs. Drain Current

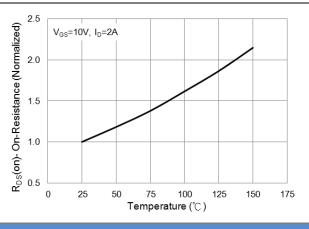


Fig.4 On-Resistance vs. Junction Temperature

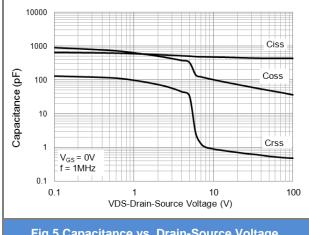


Fig.5 Capacitance vs. Drain-Source Voltage

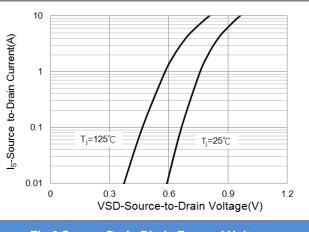


Fig.6 Source-Drain Diode Forward Voltage





## PJU4NA60 / PJD4NA60 / PJF4NA60

#### **TYPICAL CHARACTERISTIC CURVES**

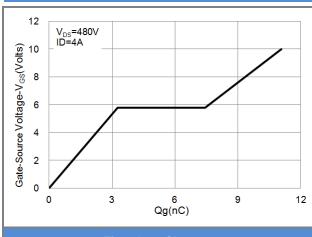


Fig.7 Gate Charge

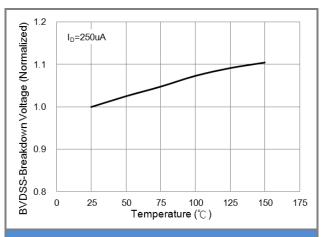


Fig.8 BV<sub>DSS</sub> vs. Junction Temperature

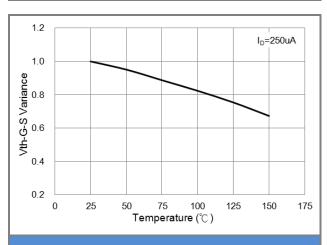


Fig.9 Threshold Voltage Variation with Temperature

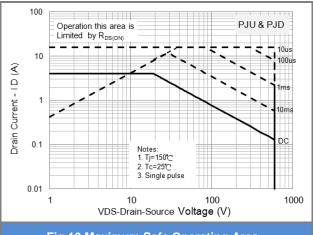
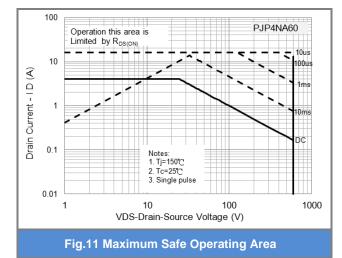


Fig.10 Maximum Safe Operating Area



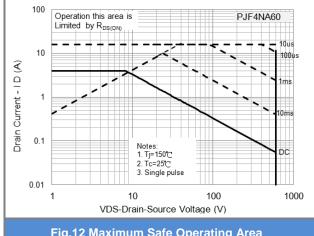
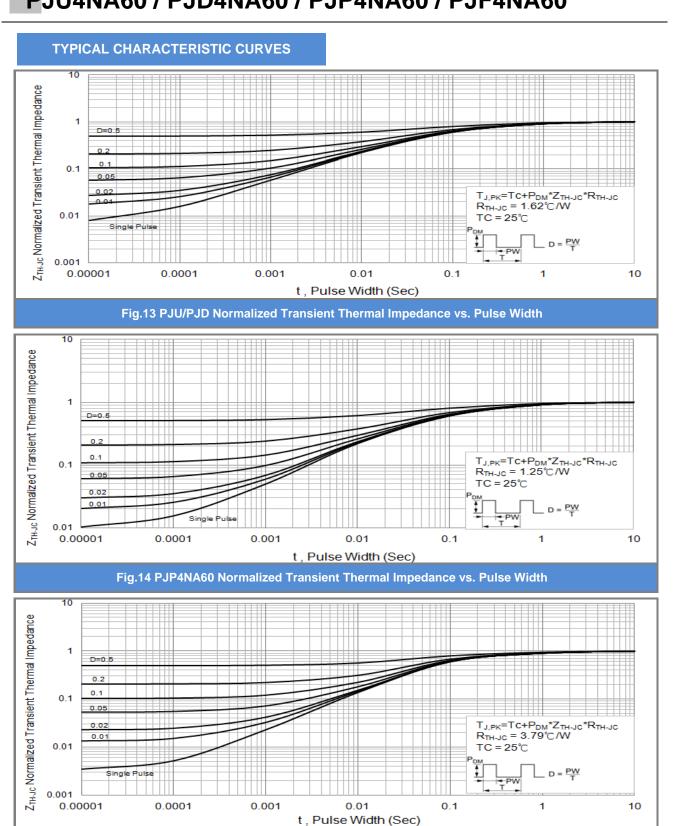


Fig.12 Maximum Safe Operating Area







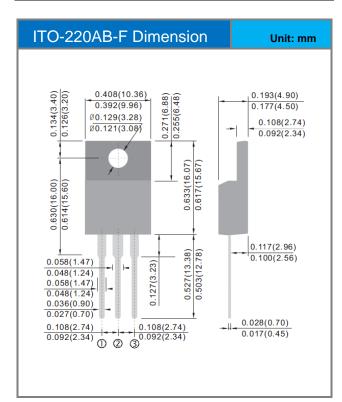
March 10,2014-REV.00 Page 5

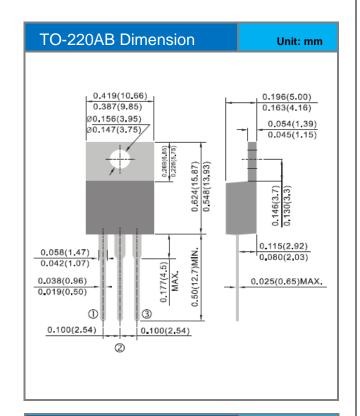
Fig.15 PJF4NA60 Normalized Transient Thermal Impedance vs. Pulse Width

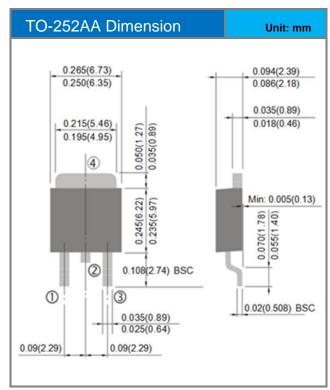


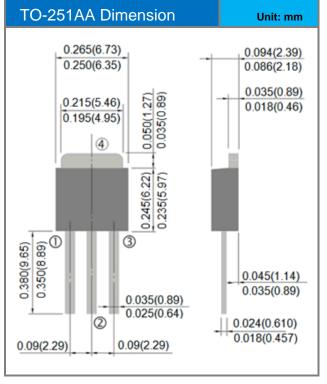


### **Packaging Information**













#### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version	
PJU4NA60_T0_00001	TO-251AA	80pcs / Tube	U4NA60	Halogen free	
PJD4NA60_L2_00001	TO-252AA	3,000pcs / 13" reel	D4NA60	Halogen free	
PJP4NA60_T0_00001	TO-220AB	50pcs / Tube	P4NA60	Halogen free	
PJF4NA60_T0_00001	ITO-220AB-F	50pcs / Tube	F4NA60	Halogen free	





#### Disclaimer

- Reproducing and modifying information of the document is prohibited without permission from Panjit International Inc..
- Panjit International Inc. reserves the rights to make changes of the content herein the document anytime without notification. Please refer to our website for the latest document.
- Panjit International Inc. disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially occurred.
- Panjit International Inc. does not assume any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.
- Applications shown on the herein document are examples of standard use and operation. Customers are
  responsible in comprehending the suitable use in particular applications. Panjit International Inc. makes no
  representation or warranty that such applications will be suitable for the specified use without further testing or
  modification.
- The products shown herein are not designed and authorized for equipments requiring high level of reliability or relating to human life and for any applications concerning life-saving or life-sustaining, such as medical instruments, transportation equipment, aerospace machinery et cetera. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Panjit International Inc. for any damages resulting from such improper use or sale.
- Since Panjit uses lot number as the tracking base, please provide the lot number for tracking when complaining.